

D1
C2

a second electrode on said upper layer insulating film and comprising the same transparent conductive film as in said transparent electrode; and at least a portion of said upper layer insulating film formed between said first electrode and said second electrode.

C2
Sub
D2

14. (Twice Amended) A method for producing the liquid-crystal display device of claim 1, comprising:

forming a plurality of address wirings on an insulating substrate;
forming a gate insulating film on said address wirings;
forming a plurality of data wiring on said gate insulating film, so that said data wirings and said address wirings cross each other;
forming a thin-film transistor for selectively connecting said data wirings with said transparent electrode disposed in each picture element area by a gate connected to said address wirings, in each picture element area surrounded by said address wirings and data wirings;
forming a first electrode using the same conductive film as used to form said data wirings;
forming an upper layer insulating film on said first electrode, said upper layer insulating film having a smaller thickness than the gate insulating film;
forming a second electrode using the same transparent conductive film as used to form said transparent electrode; and
forming said capacitor section using said first electrode, said second electrode, and said upper layer insulating film.

C3
Sub
D3

18. (Twice Amended) A method for producing the liquid-crystal display device of claim 11, comprising:

forming a plurality of address wirings on an insulating substrate;
forming a plurality of auxiliary capacitive common wiring parallel with said address wirings;

D3

forming a gate insulating film on said auxiliary capacitive common wiring;
forming a plurality of data wirings on said gate insulating film, so that said address wirings and data wirings cross each other;
forming a thin-film transistor for selectively connecting said data wirings with said transparent electrode in each picture element area by a gate connected to said address wirings, in each picture element area surrounded by said address wirings and data wirings;
forming said first electrode using the same conductive film as used to form said data wirings;
forming said upper insulating film on said first electrode, said upper layer insulating film having a smaller thickness than the gate insulating film;
forming said second electrode using the same transparent conductive film as used to form said transparent electrode; and
forming said capacitor section using said first electrode, said second electrode and said upper layer insulating film so that said capacitor is one of partially and totally superimposed on said auxiliary capacitive common wiring.

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20. (Twice Amended) A method for producing the liquid-crystal display device of claim 4, comprising:

forming a plurality of address wirings on an insulating substrate;
forming a gate insulating film on said address wirings;
forming, in said gate insulating film, a through hole which extends to said address wirings;
forming a plurality of data wirings on said gate insulating film so that said address wirings and data wirings cross each other;
forming a thin-film transistor for selectively connecting said data wirings with said transparent electrode in each picture element area by a gate connected to said address wirings, in each picture element area surrounded by said address wirings and data wirings;
forming said first electrode using the same conductive film used to form said data wirings;
connecting said first electrode to said address wirings via said through hole formed in

said gate insulating film;

forming said upper layer insulating film on said first electrode, said upper layer insulating film having a smaller thickness than the gate insulating film;

forming said second electrode using the same transparent conductive film used to form said transparent electrode; and

forming said capacitor section using said first electrode, said second electrode and said upper layer insulating film.

22. (Amended) A method of fabricating a liquid-crystal display device, said method comprising:

forming a plurality of address wirings on an insulating substrate;

forming a gate insulating film on said address wirings;

forming a plurality of data wirings on said gate insulating film, so that said data wirings and said address wirings cross each other;

forming a thin-film transistor for selectively connecting said data wirings with a transparent electrode by a gate connected to said address wirings, said transparent electrode being located in a picture element area surrounded by said address wirings and data wirings;

forming a first electrode using the same conductive film as used to form said data wirings;

forming an upper layer insulating film on said first electrode, said upper layer insulating film having a smaller thickness than the gate insulating film;

forming a second electrode using the same transparent conductive film as used to form said transparent electrode; and

forming a capacitor section using said first electrode, said second electrode, and said upper layer insulating film.